

# TK200E65Z5

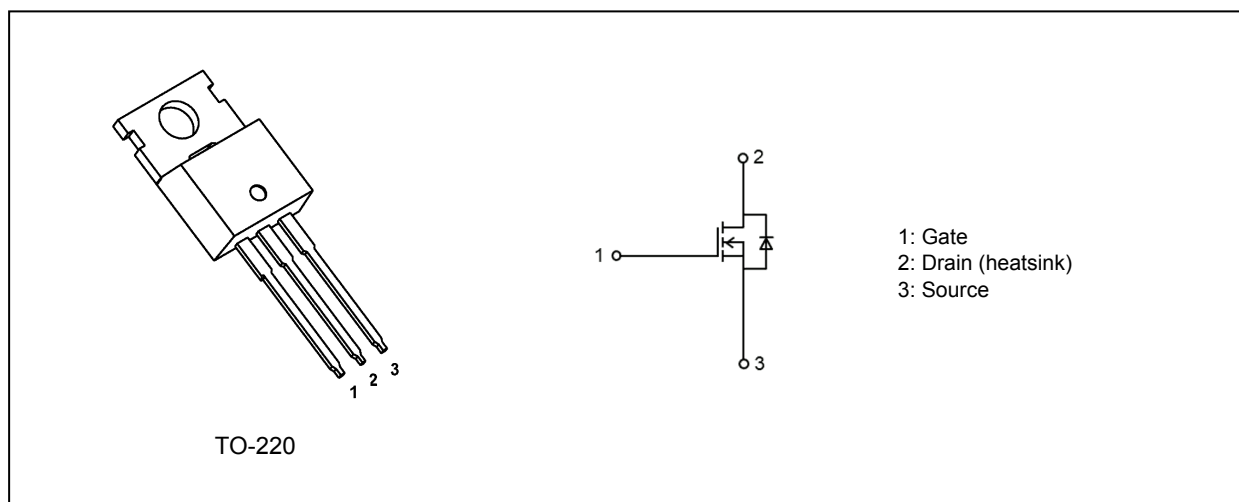
## 1. Applications

- Switching Voltage Regulators

## 2. Features

- (1) Fast reverse recovery time:  $t_{rr} = 95 \text{ ns}$  (typ.)
- (2) Low drain-source on-resistance:  $R_{DS(ON)} = 0.154 \Omega$  (typ.)
- (3) High-speed switching properties with lower capacitance.
- (4) Enhancement mode:  $V_{th} = 3.5 \text{ to } 4.5 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 0.61 \text{ mA}$ )

## 3. Packaging and Internal Circuit



Start of commercial production

2024-11

#### 4. Absolute Maximum Ratings (Note) ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DS}$	650	V
Gate-source voltage	$V_{GS}$	$\pm 30$	
Drain current (DC) (Note 1)	$I_D$	15	A
Drain current (pulsed) (Note 1)	$I_{DP}$	60	
Power dissipation ( $T_c = 25\text{ }^{\circ}\text{C}$ )	$P_D$	130	W
Single-pulse avalanche energy (Note 2)	$E_{AS}$	204	mJ
Single-pulse avalanche current	$I_{AS}$	3	A
Reverse drain current (DC) (Note 1)	$I_{DR}$	15	
Reverse drain current (pulsed) (Note 1)	$I_{DRP}$	60	
Channel temperature	$T_{ch}$	150	$^{\circ}\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	
Mounting torque	TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	0.961	$^{\circ}\text{C}/\text{W}$
Channel-to-ambient thermal resistance	$R_{th(ch-a)}$	83.3	

Note 1: Ensure that the channel temperature does not exceed  $150\text{ }^{\circ}\text{C}$ .

Note 2:  $V_{DD} = 90\text{ V}$ ,  $T_{ch} = 25\text{ }^{\circ}\text{C}$  (initial),  $L = 40.2\text{ mH}$ ,  $I_{AS} = 3\text{ A}$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

#### 6. Electrical Characteristics

##### 6.1. Static Characteristics ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 30\text{ V}$ , $V_{DS} = 0\text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 650\text{ V}$ , $V_{GS} = 0\text{ V}$	—	—	100	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}$ , $V_{GS} = 0\text{ V}$	650	—	—	V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}$ , $I_D = 0.61\text{ mA}$	3.5	—	4.5	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 10\text{ V}$ , $I_D = 7.5\text{ A}$	—	0.154	0.200	$\Omega$

6.2. Dynamic Characteristics (T<sub>a</sub> = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 300 V, V <sub>GS</sub> = 0 V, f = 100 kHz	—	1400	—	pF
Reverse transfer capacitance	C <sub>rss</sub>		—	1.2	—	
Output capacitance	C <sub>oss</sub>		—	38	—	
Effective output capacitance (energy related) (Note 3)	C <sub>O(er)</sub>	V <sub>DS</sub> = 0 to 400 V, V <sub>GS</sub> = 0 V	—	58	—	pF
Effective output capacitance (time related) (Note 4)	C <sub>O(tr)</sub>	V <sub>DS</sub> = 0 to 400 V, V <sub>GS</sub> = 0 V	—	375	—	
Gate resistance	r <sub>g</sub>	V <sub>DS</sub> = OPEN , f = 1 MHz	—	2.8	—	Ω
Switching time (rise time)	t <sub>r</sub>	See Fig. 6.2.1	—	18	—	ns
Switching time (turn-on time)	t <sub>on</sub>		—	40	—	
Switching time (fall time)	t <sub>f</sub>		—	4.4	—	
Switching time (turn-off time)	t <sub>off</sub>		—	60	—	
MOSFET dv/dt ruggedness	dv/dt	V <sub>DS</sub> ≤ V <sub>DSS</sub> , I <sub>D</sub> ≤ 7.5 A	90	—	—	V/ns

Note 3: C<sub>O(er)</sub> is a fixed capacitance that gives the same stored energy as C<sub>OSS</sub> while V<sub>DS</sub> is rising from 0 V to 400 V.

Note 4: C<sub>O(tr)</sub> is a fixed capacitance that gives the same charging time as C<sub>OSS</sub> while V<sub>DS</sub> is rising from 0 V to 400 V.

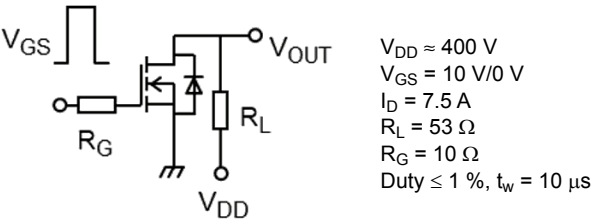


Fig. 6.2.1 Switching Time Test Circuit

## 6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400\text{ V}$ , $V_{GS} = 10\text{ V}$ , $I_D = 15\text{ A}$	—	26	—	nC
Gate-source charge 1	$Q_{gs1}$		—	8.8	—	
Gate-drain charge	$Q_{gd}$		—	8.8	—	

## 6.4. Source-Drain Characteristics ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage	$V_{DSF}$	$I_{DR} = 15\text{ A}$ , $V_{GS} = 0\text{ V}$	—	—	-1.7	V
Reverse recovery time (Note 5)	$t_{rr}$	$V_{DD} = 400\text{ V}$ , $I_{DR} = 7.5\text{ A}$ , $V_{GS} = 0\text{ V}$ $-dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	95	152	ns
Reverse recovery charge	$Q_{rr}$		—	0.4	—	$\mu\text{C}$
Peak reverse recovery current	$I_{rr}$		—	8.4	—	A
Diode dv/dt ruggedness	dv/dt	$V_{DD} \leq 400\text{ V}$ , $I_{DR} \leq 7.5\text{ A}$ , $V_{GS} = 0\text{ V}$	70	—	—	V/ns

Note 5: Defined by design.

## 7. Marking

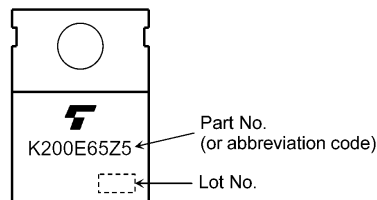


Fig. 7.1 Marking

8. Characteristics Curves (Note)

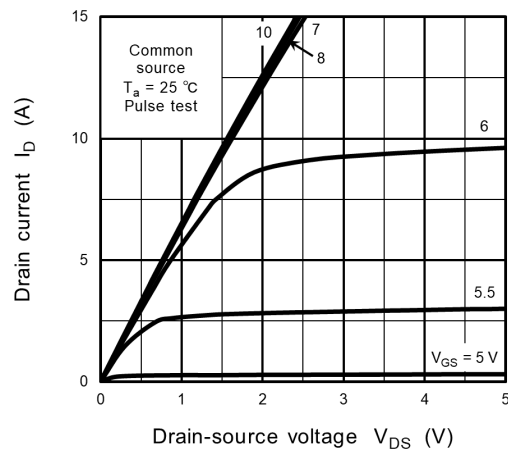


Fig. 8.1  $I_D - V_{DS}$

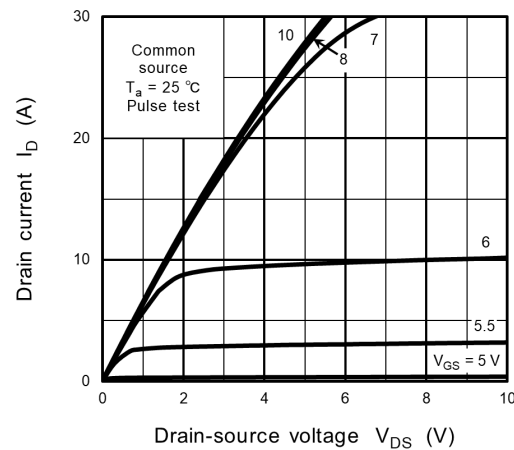


Fig. 8.2  $I_D - V_{DS}$

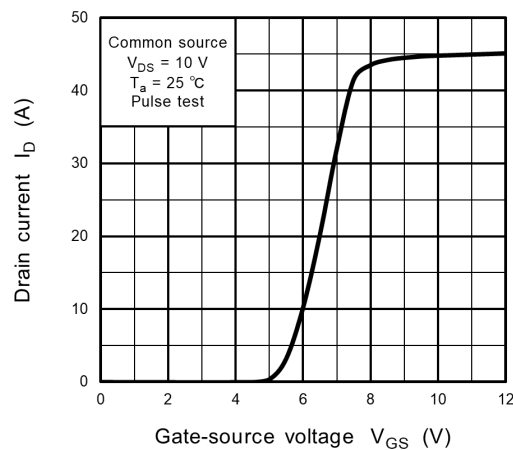


Fig. 8.3  $I_D - V_{GS}$

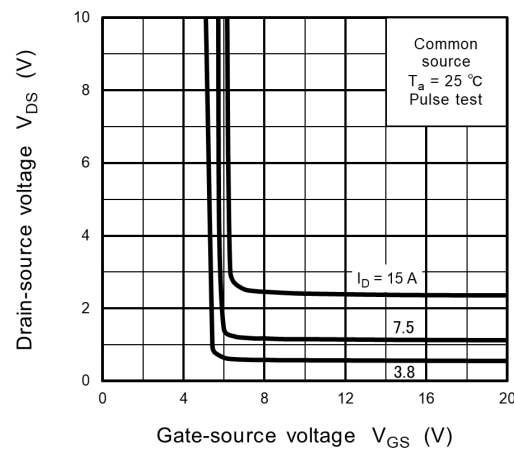


Fig. 8.4  $V_{DS} - V_{GS}$

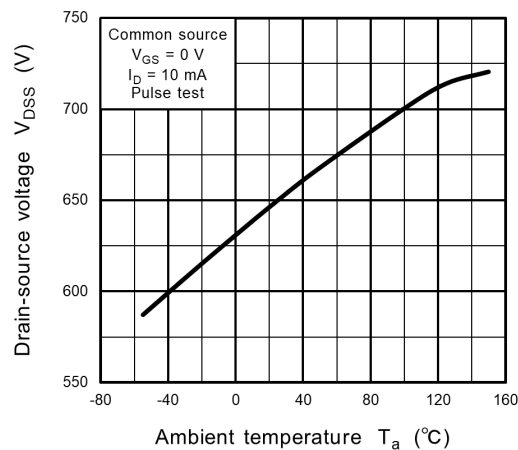


Fig. 8.5  $V_{DS} - T_a$

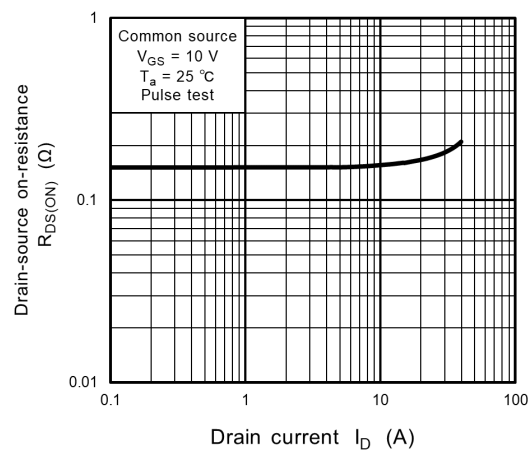


Fig. 8.6  $R_{DS(ON)} - I_D$

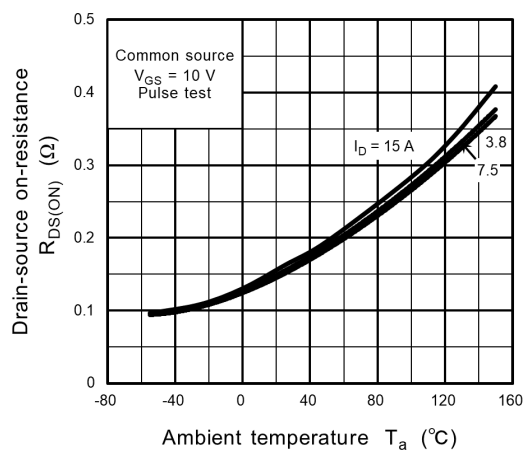


Fig. 8.7  $R_{DS(ON)} - T_a$

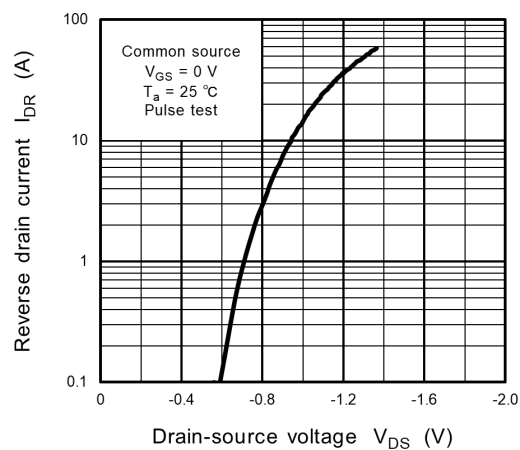


Fig. 8.8  $I_{DR} - V_{DS}$

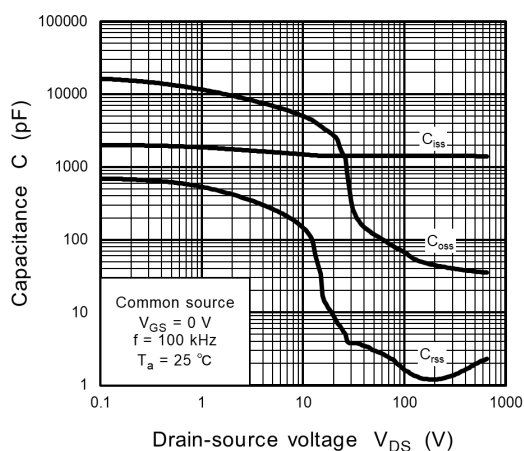


Fig. 8.9  $C - V_{DS}$

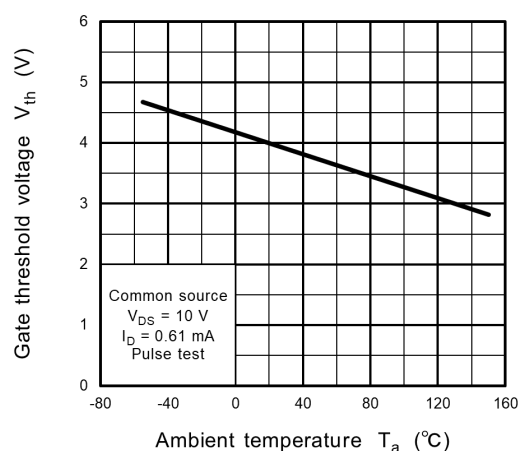


Fig. 8.10  $V_{th} - T_a$

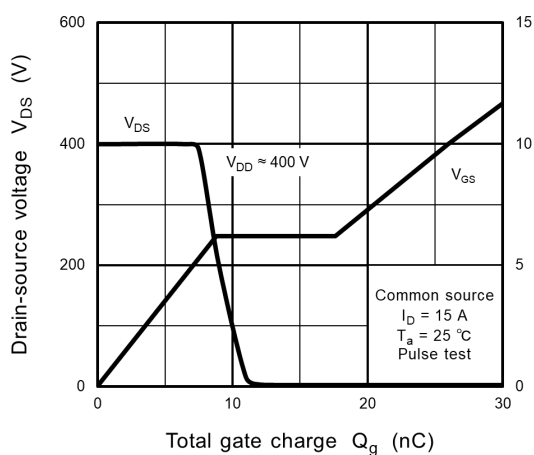


Fig. 8.11 Dynamic Input/Output Characteristics

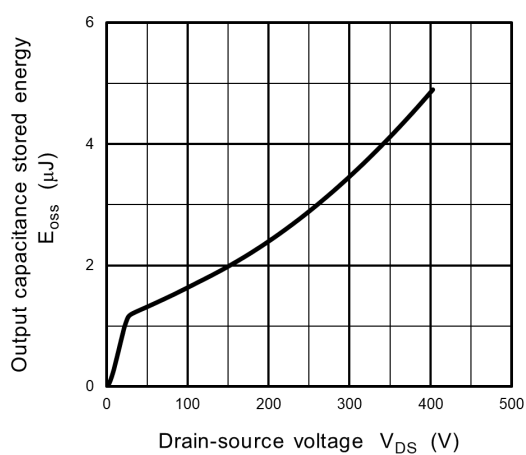


Fig. 8.12  $E_{oss} - V_{DS}$

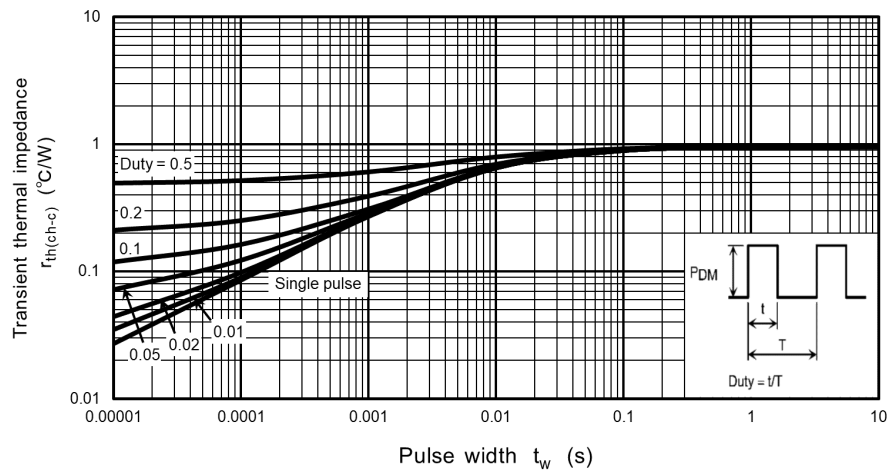


Fig. 8.13  $r_{th} - t_w$   
(Guaranteed Maximum)

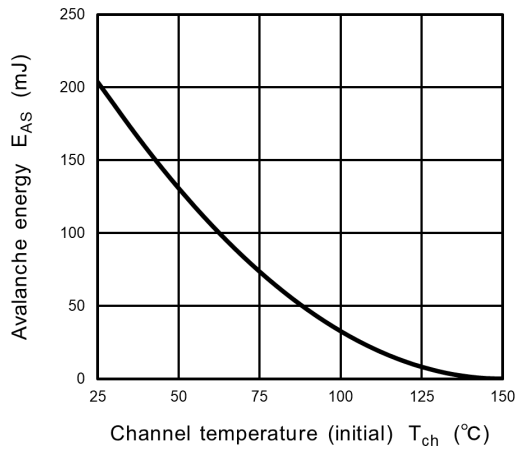


Fig. 8.14  $E_{AS} - T_{ch}$   
(Guaranteed Maximum)

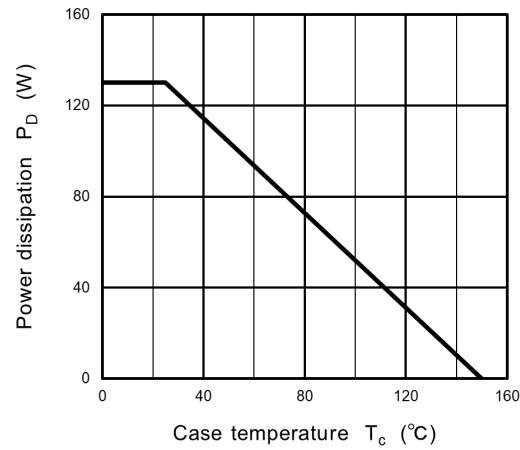


Fig. 8.15  $P_D - T_c$   
(Guaranteed Maximum)

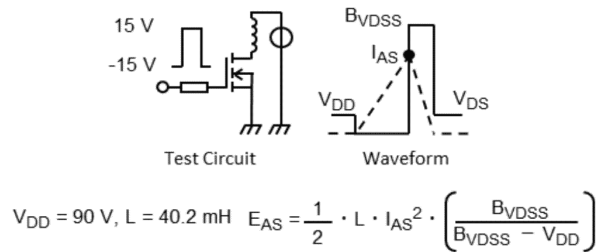


Fig. 8.16 Test Circuit/Waveform

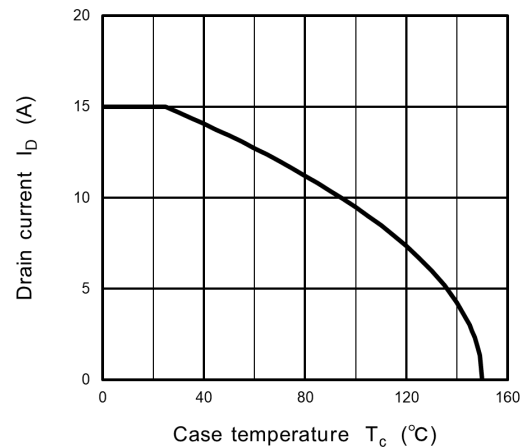
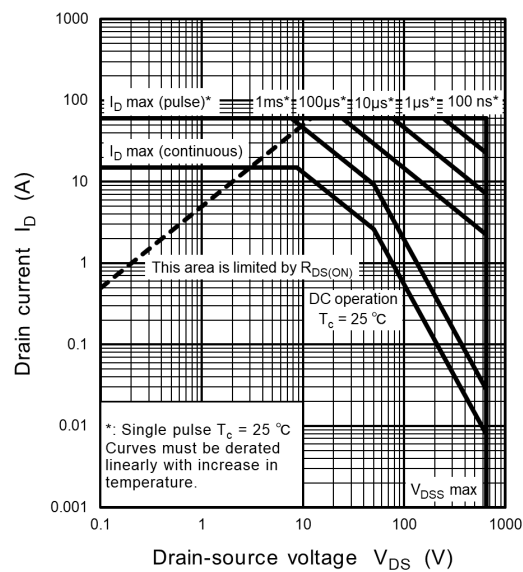


Fig. 8.17  $I_D - T_c$   
(Guaranteed Maximum)



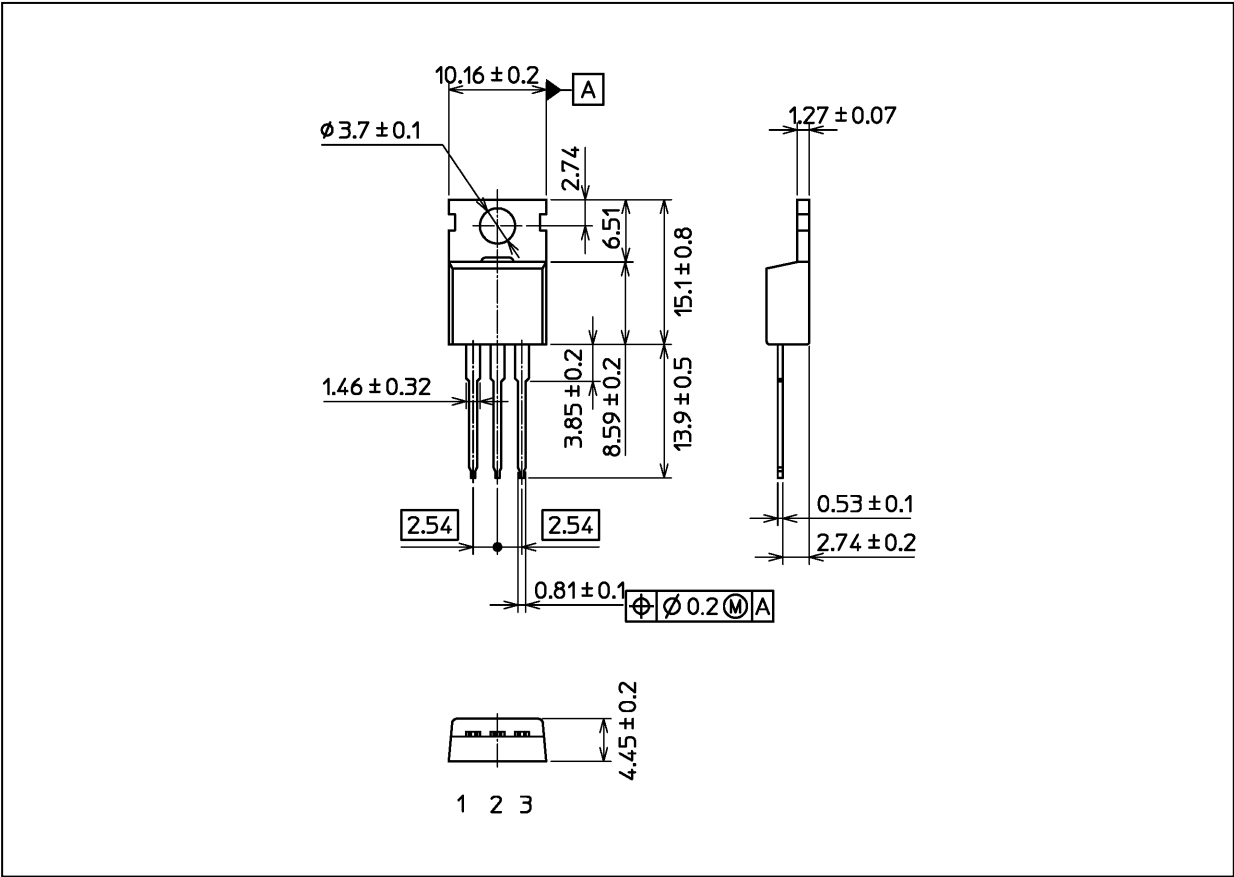
**Fig. 8.18 Safe Operating Area  
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 1.93 g (typ.)

Package Name(s)
TOSHIBA: 2-10X1A
Nickname: TO-220

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